Supporting Information Designed Multi-Layer Buffer for High-Performance

Semitransparent Wide-Bandgap Perovskite Solar Cells

Junjie Lou,^{ab} Jiangshan Feng,^{*a} Yang Cao,^a Yucheng Liu,^a Yong Qin,^{*b} and Shengzhong (Frank) Liu^{*acd}

^a Laboratory of Applied Surface and Colloid Chemistry, Ministry of Education; School of Materials Science and Engineering; Shaanxi Key Laboratory for Advanced Energy Devices; Shaanxi Engineering Lab for Advanced Energy Technology; Institute for Advanced Energy Materials, Shaanxi Normal University, Xi'an 710119, Shaanxi, China.

Email: fengjs@snnu.edu.cn

^b Institute of Nanoscience and Nanotechnology, School of Materials and Energy, Lanzhou University, Lanzhou, Gansu 730000, China. Email: qinyong@lzu.edu.cn
^c Dalian National Laboratory for Clean Energy, iChEM, Dalian Institute of Chemical Physics, Chinese Academy of Sciences, 457 Zhongshan Road, Dalian 116023, China. Email: szliu@dicp.ac.cn
^d University of Chinese Academy of Sciences, Beijing 100049, China.

*Corresponding author.



Figure S1. Statistical photovoltaic parameters of ST-PSCs based on different buffers: ZnO, ZnO/BCP or ZnO/BCP/Ag. The data were collected from 15 cells for each kind of ST-PSCs.



Figure S2. Forward (V_{oc} =1.05 V, J_{sc} =20.71 mA cm⁻², FF= 58.10%, PCE=12.68%) and reverse (V_{oc} =1.08 V, J_{sc} =20.36 mA cm⁻², FF= 70.21%, PCE=15.44%) direction scanned *J-V* curves for ST-PSCs with effective area of 1 cm².



Figure S3. (a, b) J-V curves and their partial enlarged drawing of filtered silicon cell with different thickness of MgF₂ on TCO side of filter.

	A ₁	τ_1 (ns)	A_2	$\tau_2(ns)$	$\tau_{ave} (ns)$	y0
ZnO	0.940	1.40	0.060	36.0	22.90	0.010
ZnO/BCP	0.955	1.35	0.045	36.0	20.65	0.008
ZnO/BCP/Ag	0.965	1.35	0.035	36.0	18.39	0.008

Table 1. Summary of lifetime parameters extracted from fitting curves of TRPL file.